


[Home](#) > [2N4863 \(#23222\)](#)

## 2N4863 (#23222)

### Products

- ▶ [Product Directory](#)
- ▶ [Applications Directory](#)
- ▶ [Parametric Search](#)

#### Overview

#### Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			0.20	V
DC Current Gain	HFE	50.00		150.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			140.00	V
Collector Current (dc)	$I_C$			2.00	A
Collector-Emitter Voltage (Base Open)	$V_{CEO}$			120.00	V
Emitter-Base Voltage (Collector Open)	$V_{EBO}$			8.00	V
Power Dissipation, Total	$P_T$			7.00	W

This part can be found in the following product categories:

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